



#### **60V N-Channel Enhancement Mode MOSFET**

Voltage

60 V

Current

16 A

#### **Features**

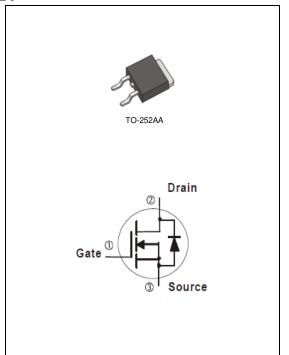
- $R_{DS(ON)}$ ,  $V_{GS}@10V$ ,  $I_D@8A<50m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}$ @4.5V,  $I_{D}$ @4A<60m $\Omega$
- High switching speed
- Improved dv/dt capability
- Low reverse transfer capacitance
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard



• Case: TO-252AA Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0104 ounces, 0.297grams



# **Maximum Ratings and Thermal Characteristics** ( $T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		$V_{DS}$	60	· V	
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20	٧	
Continuous Drain Current (Note 4)	T <sub>C</sub> =25°C	I <sub>D</sub>	16	А	
	T <sub>C</sub> =100°C		10		
Pulsed Drain Current (Note 1)	T <sub>C</sub> =25°C	I <sub>DM</sub>	64		
Power Dissipation	T <sub>C</sub> =25°C	Po	32.6	W	
	T <sub>C</sub> =100°C		16.3		
Continuous Drain Current (Note 4)	T <sub>A</sub> =25°C	I <sub>D</sub>	4.4	А	
	T <sub>A</sub> =70°C		3.5		
Power Dissipation	T <sub>A</sub> =25°C	P <sub>D</sub>	2.4	W	
	T <sub>A</sub> =70°C		1.6		
Single Pulse Avalanche Energy (Note 6)		E <sub>AS</sub>	11	mJ	
Operating Junction and Storage Temperature Range		$T_{J}$ , $T_{STG}$	-55~175	°C	
Typical Thermal Resistance (Note 4,5)	Junction to Case	$R_{ heta JC}$	4.6	°C/W	
	Junction to Ambient	$R_{ heta JA}$	62.5		

• Limited only By Maximum Junction Temperature





### **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	$V_{GS}$ =0V, $I_D$ =250uA	60	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250uA$	1	1.77	2.5		
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	$V_{GS}=10V$ , $I_D=8A$	-	37	50	mΩ	
		$V_{GS}$ =4.5V, $I_D$ =4A	-	42	60		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ =60V, $V_{GS}$ =0V	-	-	1	uA	
Gate-Source Leakage Current	$I_{GSS}$	$V_{GS} = \pm 20V, V_{DS} = 0V$	-	-	<u>+</u> 100	nA	
Dynamic (Note 7)							
Total Gate Charge	$Q_g$	$V_{DS}=30V, I_{D}=4A, V_{GS}=10V^{(Note 1,2)}$	-	14	-	nC	
Gate-Source Charge	$Q_{gs}$		-	2.9	-		
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =10V	-	2.3	-		
Input Capacitance	Ciss	\\\ 45\\\\\\ 0\\	-	815	-	pF	
Output Capacitance	Coss	$V_{DS}=15V, V_{GS}=0V,$	-	379	-		
Reverse Transfer Capacitance	Crss	f=1MHZ	-	110	-		
Turn-On Delay Time	td <sub>(on)</sub>	\/ 00\/   4A	-	3.9	-	ns	
Turn-On Rise Time	t <sub>r</sub>	$V_{DD}$ =30V, $I_{D}$ =1A, $V_{GS}$ =10V, $R_{G}$ =3.3 $\Omega$	-	13	-		
Turn-Off Delay Time	td <sub>(off)</sub>		-	23	-		
Turn-Off Fall Time	t <sub>f</sub>		-	6.7	-		
Drain-Source Diode							
Maximum Continuous Drain-Source					16	Α	
Diode Forward Current	I <sub>S</sub>		-	-	10	A	
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =1A, V <sub>GS</sub> =0V	-	0.73	1	V	

#### NOTES:

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature  $T_{J(MAX)}$ =150°C. Ratings are based on low frequency and duty cycles to keep initial  $T_J$  =25°C.
- 4. The maximum current rating is package limited.
- 5. Reja is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
- 6. The test condition is L=0.1mH,  $I_{AS}$ =15A,  $V_{DD}$ =25V,  $V_{GS}$ =10V.
- 7. Guaranteed by design, not subject to production testing.





#### **TYPICAL CHARACTERISTIC CURVES**

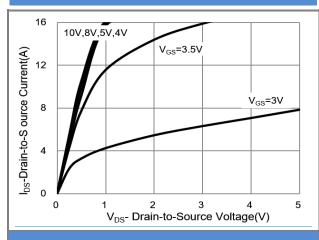
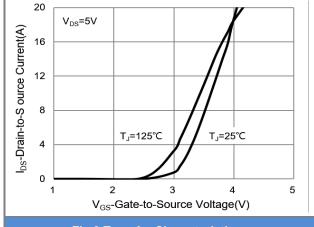


Fig.1 Output Characteristics



**Fig.2 Transfer Characteristics** 

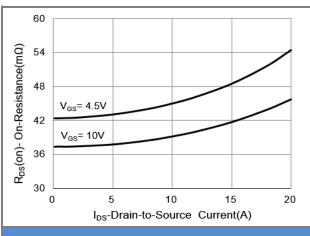


Fig.3 On-Resistance vs. Drain Current

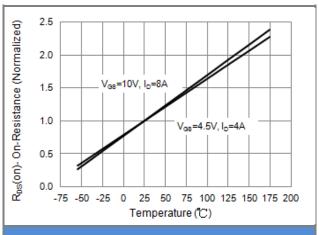
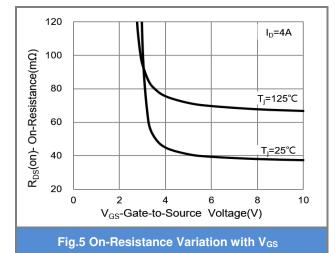


Fig.4 On-Resistance vs. Junction temperature



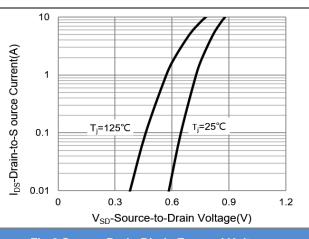


Fig.6 Source-Drain Diode Forward Voltage





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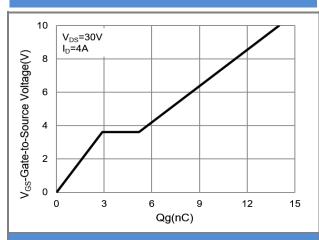


Fig.7 Gate-Charge Characteristics

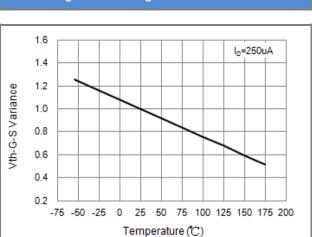


Fig.9 Threshold Voltage Variation with Temperature

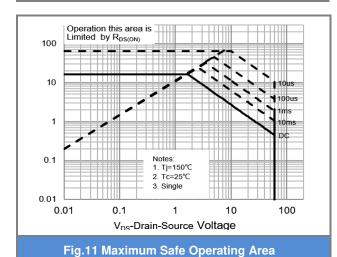


Fig.8 Breakdown Voltage Variation vs. Temperature

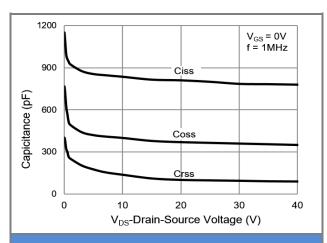


Fig.10 Capacitance vs. Drain-Source Voltage





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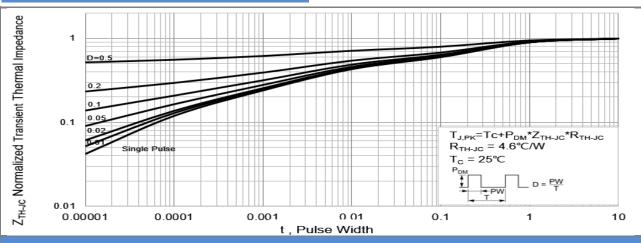


Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width

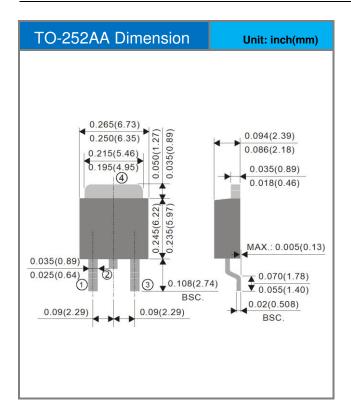


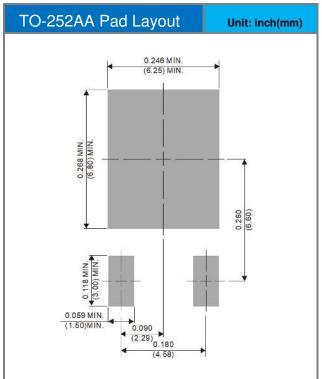


#### **Part No Packing Code Version**

Part No Packing Code	Package Type	Packing Type	Marking	Version	
PJD16N06A-AU_L2_000A1	TO-252AA	3,000pcs / 13" reel	D16N06A	Halogen free	

### **Packaging Information & Mounting Pad Layout**









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